

First Named Inventor	Chun Chen
erial No.	10/662,074
Filing Date	September 12, 2003
Group Art Unit	Unknown
Examiner Name	Unknown
Confirmation No.	9792
Attorney Docket No.	400 1811303

CONTACTLESS UNIFORM TUNNELING SEPARATE P-WELL (CUSP) NON-VOLATILE MEMORY ARRAY ARCHITECTURE, FABRICATION AND OPERATION

U.S. Patent References				
Examiner Initials	Document No.	Issue/Published Date	Name	Filing Date
W	5,343,423	08/30/94	Shimoji	12/23/91
W	5,691,938	11/25/97	Yiu et al.	05/03/94
21	6,137,723	10/24/00	Bergemont et al.	04/28/99
ન	6,181,601 B1	01/30/01	Chi	12/02/99

	Foreign Patent References					
Examiner	Foreign Pat	ent		Name	Publication Date	T?
Initials	Country	No.				

	Other References
Examiner Initials	Author, Title, Date, Pages, etc.
4	S. Aritome, et al. "A reliable bi-polarity write/erase technology in flash EEPROMS", Int'l. Electron Devices Meeting, 1990, <u>Technical Digest</u> , 9-12 Dec. 1990; pp. 111-114.

Examiner Signature Wicker	Date Considered	9/13/4
*Examiner: Initial if citation considered, whether or not citation is in conformation	ace with MPEP 60	9; Draw line through citation if not

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Based on Form PTO-FB-A820 Patent and Trademark Office, U.S. Department of Commerce



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21	5,945,698	08/31/99	Prall	07/01/97		
	5,973,352	10/26/99	Noble	08/20/97		
	5,973,356	10/26/99	Noble	07/08/97		
	6,080,672	06/27/00	Juengling	08/20/97		
	6,160,277	12/12/00	Prall	03/19/99		
	6,191,444 B1	02/20/01	Clampitt	09/03/98		
	6,218,698 B1	04/17/01	Hai	08/17/98		
	6,272,047 B1	08/07/01	Mihnea	12/17/99		
	6,319,774 B1	11/20/01	Hai	02/27/98		
	6,337,244 B1	01/08/02	Prall	03/01/00		
	6,406,959 B2	06/18/02	Prall	01/04/99		
	6,441,428 B1	08/27/02	Ghodsi	03/19/01		
	6,489,665 B2	12/03/02	Prall	12/20/00		
	2002/0044483 A1	04/18/02	Prall	08/28/01		
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